











TPS7A8101-Q1

SLVSCK0A - APRIL 2014-REVISED JUNE 2014

TPS7A8101-Q1 Low-Noise, Wide-Bandwidth, High PSRR, **Low-Dropout 1-A Linear Regulator**

Features

- **Qualified for Automotive Applications**
- AEC-Q100 Qualified With the Following Results:
 - Device Temperature Grade 1: –40°C to 125°C Ambient Operating Temperature Range
 - Device HBM ESD Classification Level H2
 - Device CDM ESD Classification Level C4B
- Low-Dropout 1-A Regulator with Enable
- Adjustable Output Voltage: 0.8 V to 6 V
- Wide-Bandwidth High PSRR:
 - 80 dB at 1 kHz
 - 60 dB at 100 kHz
 - 54 dB at 1 MHz
- Low Noise: 23.5 μV_{RMS} typical (100 Hz to 100 kHz)
- Stable With 4.7-µF Output Capacitance
- **Excellent Load and Line Transient Response**
- 3% Overall Accuracy (Over Load, Line, Temperature)
- Over-Current and Overtemperature Protection
- Very Low Dropout: 170 mV Typical at 1 A
- Package: 3-mm x 3-mm SON-8

2 Applications

- RF Power in Automotive Applications
- Automotive ADAS ECUs
- **Telematic Control Units**
- High-Speed I/F (PLL and VCO)

3 Description

The TPS7A8101-Q1 low-dropout linear regulator (LDO) offers very good performance in output noise and power-supply rejection ratio (PSRR). This LDO uses an advanced BiCMOS process and a PMOSFET pass device to achieve very low noise, excellent transient response, and excellent PSRR performance.

The TPS7A8101-Q1 device is stable with a 4.7-µF ceramic output capacitor and uses a precision voltage reference and feedback loop to achieve a worst-case accuracy of 3% over all load, line, process, and temperature variations.

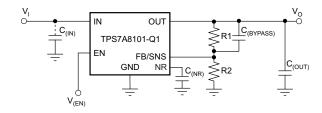
This device is fully specified over the temperature range of $T_A = -40$ °C to 125°C and is offered in a 3-mm x 3-mm, SON-8 package with a thermal pad.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS7A8101-Q1	SON (8)	3.00 mm × 3.00 mm

For all available packages, see the orderable addendum at the end of the datasheet.

Typical Application Circuit



Typical Power-Supply Ripple Rejection

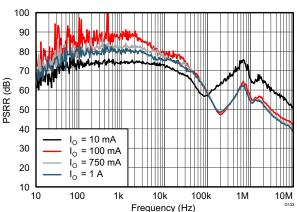




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5 Revision History

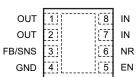
Changes from Original (April 2014) to Revision.	
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6 Pin Configuration and Functions





Pin Functions

PIN		DESCRIPTION				
NAME	NO.	DESCRIPTION				
EN	5	Driving this pin high turns on the regulator. Driving this pin low puts the regulator into shutdown mode. See to the <i>Shutdown</i> section for more details. The EN pin must not be left floating and can be connected to the IN pin if not used.				
FB/SNS 3		This pin is the input to the error amplifier and is used to set the output voltage of the device.				
GND 4		Ground				
IN	7	Unregulated input supply				
IIN	8	Onregulated input supply				
NR	6	Connect an external capacitor between this pin and ground to reduce output noise to very low levels. The capacitor also slows down the V_0 ramp (RC soft start).				
OUT	1	Degulator autout A 4.7 uE as larger paramic appositor is required for stability				
OUT	2	Regulator output. A 4.7-µF or larger ceramic capacitor is required for stability.				
Thermal Pad	_	The Thermal Pad should be connected to GND.				



7 Specifications

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted). (1)

		MIN	MAX	UNIT
	IN	-0.3	7	V
Voltage	FB/SNS, NR	-0.3	3.6	V
Voltage	EN	-0.3	$V_1 + 0.3^{(2)}$	V
	OUT	-0.3	7	V
Current	OUT	Internal	lly Limited	Α
Operating junction temperature, T _J		– 55	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated is not implied. Exposure to absolute-maximum-rated conditions for extended periods my affect device reliability.

7.2 Handling Ratings

				MIN	MAX	UNIT
T _{stg} Storage temperature range				-55	150	°C
		Human body model (HBM), per AEC Q100-002, class	fication level H2 ⁽¹⁾	-2	2	kV
V _(ESD)		Charged device model (CDM), per JEDEC	Corner pins (1, 4, 5, and 8)	-750	750	V
		specification JESD22-C101, classification level C4B	Other pins	-500	500	

⁽¹⁾ AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 Specification.

7.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{I}	Input voltage	2.2	6.5	V
Io	Output current	0	1	Α
T_A	Operating free air temperature	-40	125	°C

7.4 Thermal Information

	THERMAL METRIC ⁽¹⁾	DRB (8 PINS)	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	45.7	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	53.1	
$R_{\theta JB}$	Junction-to-board thermal resistance	21.2	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.9	C/VV
ΨЈВ	Junction-to-board characterization parameter	21.4	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	5.2	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953A.

⁽²⁾ $V_{(EN)}$ absolute maximum rating is $V_1 + 0.3$ V or + 7 V, whichever is smaller.



7.5 Electrical Characteristics

Over the temperature range of $-40^{\circ}\text{C} \le T_A$, $T_J \le 125^{\circ}\text{C}$, $V_I = V_{Onom} + 0.5 \text{ V}$ or 2.2 V (whichever is greater), $I_O = 1 \text{ mA}$, $V_{(EN)} = 2.2 \text{ V}$, $C_{(OUT)} = 4.7 \text{ }\mu\text{F}$, $C_{(NR)} = 0.01 \text{ }\mu\text{F}$, and $C_{(BYPASS)} = 0 \text{ }\mu\text{F}$, unless otherwise noted. The device is tested at $V_O = 0.8 \text{ V}$ and $V_0 = 6 \text{ V}$. Typical values are at $T_J = 25$ °C.

	PARAMETER	TEST COND	ITIONS	MIN	TYP	MAX	UNIT
VI	Input voltage range ⁽¹⁾			2.2		6.5	V
V _(NR)	Internal reference			0.79	0.8	0.81	V
	Output voltage range		0.8		6	V	
Vo	Out-11 (2)	$V_O + 0.5 \text{ V} \le V_I \le 6 \text{ V}, V_I \ge 2$ 100 mA $\le I_O \le 500$ mA, 0°C		-2%		2%	
	Output accuracy ⁽²⁾ $V_{O} + 0.5 \text{ V} \le V_{I} \le 6.5 \text{ V}, V_{I} \ge 2.2 \text{ V},$ $100 \text{ mA} \le I_{O} \le 1 \text{ A}$ $V_{O} = +0.5 \text{ V} \le V_{I} \le 6.5 \text{ V}, V_{I} \ge 2.2 \text{ V}$		2.2 V,	-3%	±0.3%	3%	
$\Delta V_{O(\Delta VI)}$	Line regulation	$V_{Onom} + 0.5 \text{ V} \le V_{I} \le 6.5 \text{ V}, V_{IO} = 100 \text{ mA}$	/ _I ≥ 2.2 V,		150		μV/V
$\Delta V_{O(\Delta IL)}$	Load regulation	100 mA ≤ I _O ≤ 1 A			2		μV/mA
		$V_0 + 0.5 \text{ V} \le V_1 \le 6.5 \text{ V}, V_1 \ge 2.2 \text{ V},$ $V_0 = 500 \text{ mA}, V_{(FB/SNS)} = \text{GND}$ $V_0 + 0.5 \text{ V} \le V_1 \le 6.5 \text{ V}, V_1 \ge 2.5 \text{ V},$				250	mV
V_{DO}	Dropout voltage (3)	$I_O = 750 \text{ mA}, V_{(FB/SNS)} = GN$	D			350	mV
	$\begin{aligned} V_O + 0.5 \ V \le V_I \le 6.5 \ V, \ V_I \ge 2.5 \ V, \\ I_O = 1 \ A, \ V_{(FB/SNS)} = GND \end{aligned}$ Output current-limit $V_O = 0.85 \times V_{O-1}, V_I \ge 3.3 \ V$				500	mV	
IL	Output current-limit	$V_{O} = 0.85 \times V_{Onom}, V_{I} \ge 3.3$	1100	1400	2000	mA	
	Cround pin ourrent	$I_O = 1 \text{ mA}$		60	100	μΑ	
I _(GND)	Ground pin current	I _O = 1 A				350	μΑ
I _{L(sd)}	Shutdown current (I _(GND))	$V_{(EN)} \le 0.4 \text{ V}, V_1 \ge 2.2 \text{ V}, R_L = 1 \text{ k}\Omega,$ $0^{\circ}\text{C} \le T_J \le 125^{\circ}\text{C}$			0.2	2.5	μΑ
I _(FB/SNS)	Feedback pin current	$V_1 = 6.5 \text{ V}, V_{(FB/SNS)} = 0.8 \text{ V}$			0.02	1	μΑ
I(FB/SNS)	Power-supply rejection ratio		f = 100 Hz		80		dB
		$V_{I} = 4.3 \text{ V}, V_{O} = 3.3 \text{ V},$ $I_{O} = 750 \text{ mA}$	f = 1 kHz		82		dB
PSRR			f = 10 kHz		78		dB
			f = 100 kHz		60		dB
			f = 1 MHz		54		dB
V _n	Output noise voltage	BW = 100 Hz to 100 kHz, V _I = 3.8 V, V _O = 3.3 V, I _O = 100 mA, C _(NR) = C _(BYPASS) = 470 nF			23.5		μV_{RMS}
V	Enable high (anabled)	$2.2 \text{ V} \le \text{V}_{\text{I}} \le 3.6 \text{ V}, \text{ R}_{\text{L}} = 1 \text{ kG}$	Ω	1.2			V
$V_{(EN)H}$	Enable high (enabled)	$3.6 \text{ V} < \text{V}_1 \le 6.5 \text{ V}, \text{ R}_L = 1 \text{ k}\Omega$		1.35			V
$V_{(EN)L}$	Enable low (shutdown)	$R_L = 1 \text{ k}\Omega$		0		0.4	V
I _(EN)	Enable pin current, enabled	V _I = V _(EN) = 6.5 V			0.02	1	μΑ
t _{st}	Startup time	$V_{Onom} = 3.3 \text{ V, } V_{O} = 0\% \text{ to } 90\% V_{Onom},$ R1 = 3.3 k Ω , $C_{(OUT)} = 10 \mu\text{F, } C_{(NR)} = 470 \text{ nF}$			80		ms
UVLO	Undervoltage lockout	V_I rising, $R_L = 1 \text{ k}\Omega$		1.86	2	2.1	V
UVLU	Hysteresis	V_I falling, $R_L = 1 \text{ k}\Omega$			75		mV
т	Thormal abutdown townsers	Shutdown, temperature incre	easing		160		°C
T _{sd}	Thermal shutdown temperature	Reset, temperature decreas		140		°C	

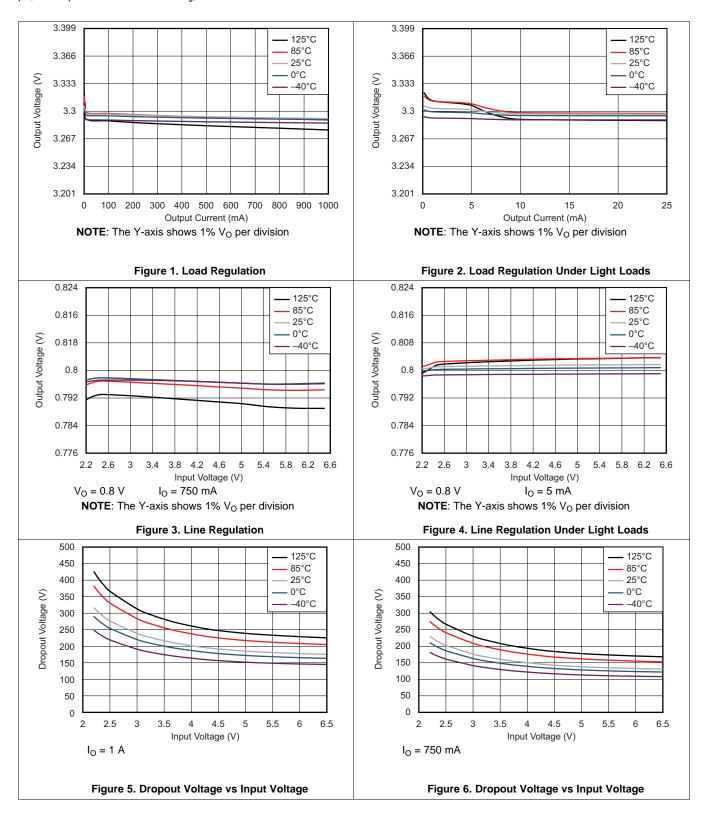
Minimum $V_I = V_O + V_{DO}$ or 2.2 V, whichever is greater. The TPS7A8101-Q1 does not include external resistor tolerances and it is not tested at this condition: $V_O = 0.8 \text{ V}$, 4.5 V $\leq V_I \leq 6.5 \text{ V}$, and 750 mA \leq I_O \leq 1 A because the power dissipation is greater than the maximum rating of the package.

 V_{DO} is not measured for fixed output voltage devices with V_{O} < 1.7 V because minimum V_{I} = 2.2 V.



7.6 Typical Characteristics

At $V_{Onom} = 3.3 \text{ V}$, $V_I = V_{Onom} + 0.5 \text{ V}$ or 2.2 V (whichever is greater), $I_O = 100 \text{ mA}$, $V_{(EN)} = V_I$, $C_{(IN)} = 1 \text{ }\mu\text{F}$, $C_{(OUT)} = 4.7 \text{ }\mu\text{F}$, and $C_{(NR)} = 0.01 \text{ }\mu\text{F}$; all temperature values refer to T_J , unless otherwise noted.



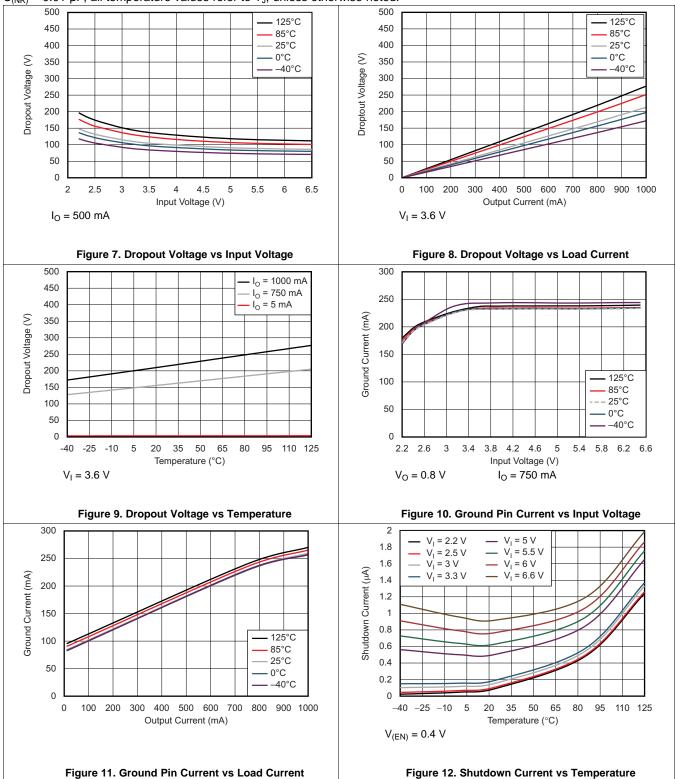
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Typical Characteristics (continued)

At V_{Onom} = 3.3 V, V_I = V_{Onom} + 0.5 V or 2.2 V (whichever is greater), I_O = 100 mA, $V_{(EN)}$ = V_I , $C_{(IN)}$ = 1 μ F, $C_{(OUT)}$ = 4.7 μ F, and $C_{(NR)}$ = 0.01 μ F; all temperature values refer to T_J , unless otherwise noted.

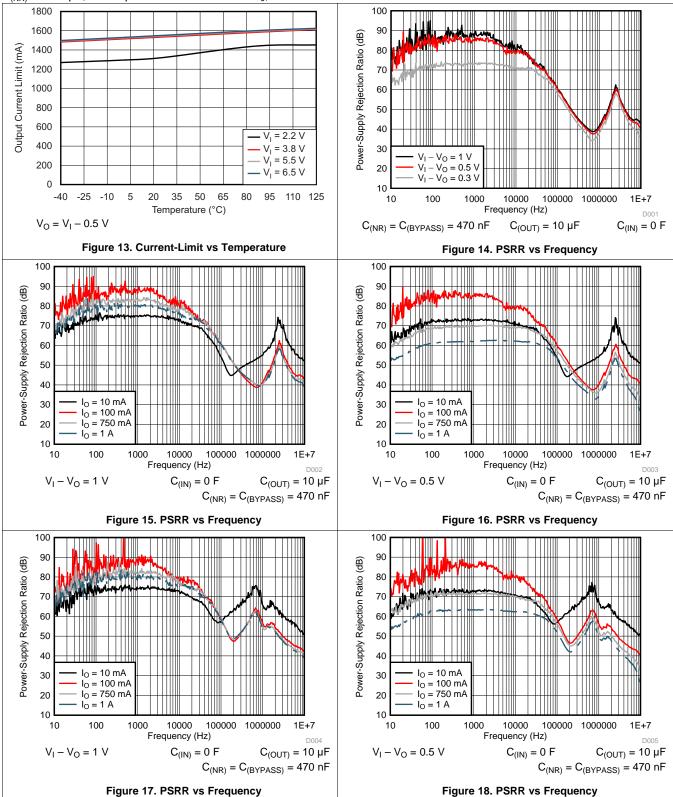


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Typical Characteristics (continued)

At V_{Onom} = 3.3 V, V_I = V_{Onom} + 0.5 V or 2.2 V (whichever is greater), I_O = 100 mA, $V_{(EN)}$ = V_I , $C_{(IN)}$ = 1 μ F, $C_{(OUT)}$ = 4.7 μ F, and $C_{(NR)}$ = 0.01 μ F; all temperature values refer to T_J , unless otherwise noted.



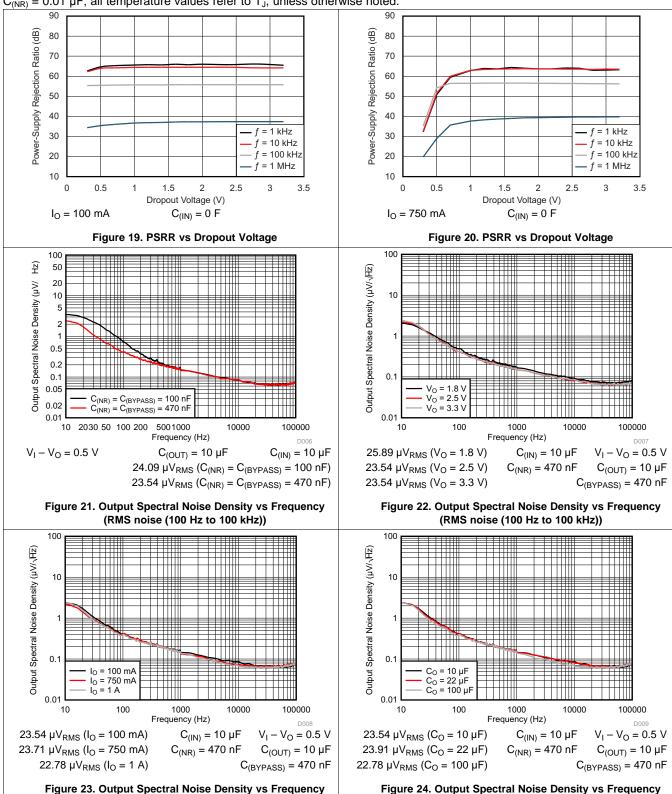
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Typical Characteristics (continued)

At V_{Onom} = 3.3 V, V_I = V_{Onom} + 0.5 V or 2.2 V (whichever is greater), I_O = 100 mA, $V_{(EN)}$ = V_I , $C_{(IN)}$ = 1 μ F, $C_{(OUT)}$ = 4.7 μ F, and $C_{(NR)}$ = 0.01 μ F; all temperature values refer to T_J , unless otherwise noted.



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(RMS noise (100 Hz to 100 kHz))

(RMS noise (100 Hz to 100 kHz))

TEXAS INSTRUMENTS

Typical Characteristics (continued)

At $V_{Onom} = 3.3 \text{ V}$, $V_I = V_{Onom} + 0.5 \text{ V}$ or 2.2 V (whichever is greater), $I_O = 100 \text{ mA}$, $V_{(EN)} = V_I$, $C_{(IN)} = 1 \text{ }\mu\text{F}$, $C_{(OUT)} = 4.7 \text{ }\mu\text{F}$, and $C_{(NR)} = 0.01 \text{ }\mu\text{F}$; all temperature values refer to T_J , unless otherwise noted.

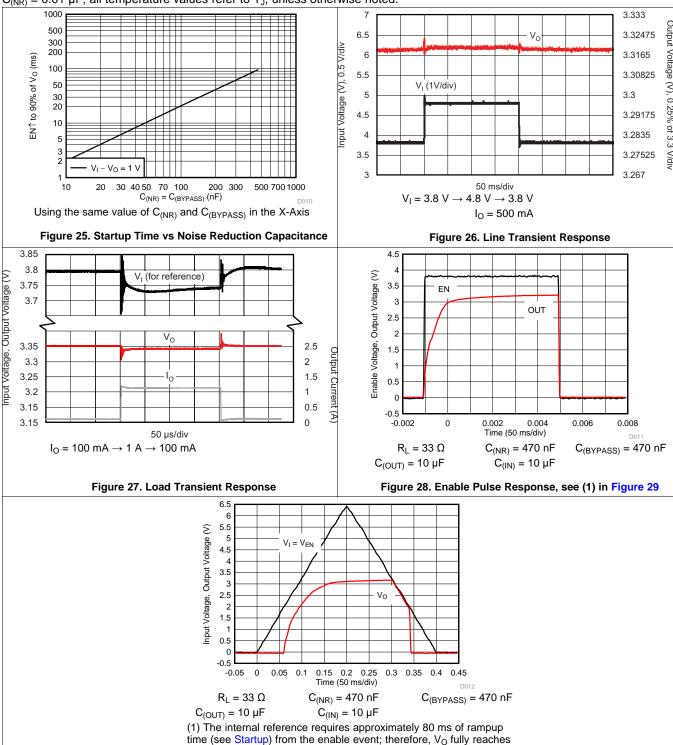


Figure 29. Power-Up and Power-Down Response

Product Folder Links: TPS7A8101-Q1

the target output voltage of 3.3 V in 80 ms from startup.



8 Detailed Description

8.1 Overview

The TPS7A8101-Q1 device belongs to a family of new-generation LDO regulators that use innovative circuitry to achieve wide bandwidth and high loop gain, resulting in extremely high PSRR (over a 1-MHz range) even with very low headroom ($V_I - V_O$). A noise-reduction capacitor ($C_{(NR)}$) at the NR pin and a bypass capacitor ($C_{(BYPASS)}$) decrease noise generated by the bandgap reference in order to improve PSRR, while a quick-start circuit fast-charges the noise-reduction capacitor. This family of regulators offers sub-bandgap output voltages, current-limit, and thermal protection, and is fully specified from -40° C to 125° C.

8.2 Functional Block Diagram

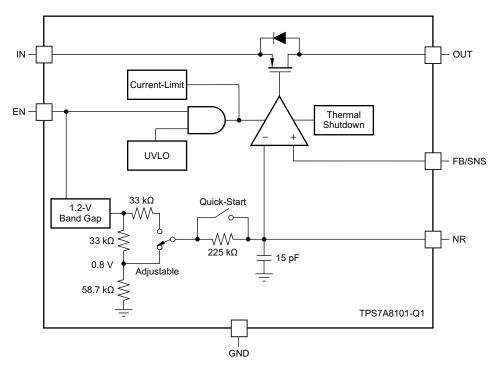


Figure 30. Functional Block Diagram

8.3 Feature Description

8.3.1 Internal Current-Limit

The TPS7A8101-Q1 internal current-limit helps protect the regulator during fault conditions. During the current-limit, the output sources a fixed amount of current that is largely independent of the output voltage. For reliable operation, the device should not be operated in a current-limit state for extended periods of time.

The PMOS pass element in the TPS7A8101-Q1 device has a built-in body diode that conducts current when the voltage at the OUT pin $(V_{(OUT)})$ exceeds the voltage at the IN pin $(V_{(IN)})$. This current is not limited, so if extended reverse-voltage operation is anticipated, external limiting may be appropriate.

8.3.2 Shutdown

The enable pin (EN) is active high and is compatible with standard-voltage and low-voltage TTL-CMOS levels. When shutdown capability is not required, the EN pin can connect to the IN pin.



Feature Description (continued)

8.3.3 Startup

Through a lower resistance, the bandgap reference can quickly charge the noise-reduction capacitor ($C_{(NR)}$). The TPS7A8101-Q1 device has a *quick-start* circuit to quickly charge $C_{(NR)}$, if present; see Figure 30. At startup, this quick-start switch is closed, with only 33 k Ω of resistance between the bandgap reference and the NR pin. The quick-start switch opens approximately 100 ms after any device-enabling event, and the resistance between the bandgap reference and the NR pin becomes higher in value (approximately 250 k Ω) to form a very-good low-pass (RC) filter. This low-pass filter reduces the noise present on the reference voltage; therefore, reducing the noise on the output.

Inrush current can cause problems in many applications. The $33-k\Omega$ resistance during the startup period is intentionally placed between the bandgap reference and the NR pin in order to slow down the reference voltage rampup, thus reducing the inrush current.

Use Equation 1 to calculate the startup time with other $C_{(NR)}$ values. For example, the capacitance of connecting the recommended $C_{(NR)}$ value of 0.47 μF along with the 33-k Ω resistance causes an 80-ms RC delay (approximately).

$$t_{st}(s) = 170000 \times C_{(NR)}(F)$$
 (1)

Although the noise-reduction effect is nearly saturated at 0.47 μ F, connecting a $C_{(NR)}$ value greater than 0.47 μ F can additionally help reduce noise. However, when connecting a $C_{(NR)}$ value greater than 0.47 μ F, the startup time is extremely long because the quick-start switch opens after approximately 100 ms. That is, if $C_{(NR)}$ is not fully charged during this 100-ms period, $C_{(NR)}$ finishes charging through a higher resistance of 250 k Ω , and takes much longer to fully charge.

NOTE

A low-leakage capacitor should be used for $C_{(NR)}$. Most ceramic capacitors are suitable

8.3.4 Undervoltage Lockout (UVLO)

The TPS7A8101-Q1 device uses an undervoltage-lockout (UVLO) circuit to ensure that the output is shut off until the internal circuitry has enough voltage to operate properly. The UVLO circuit has a deglitch feature so that the circuit typically ignores undershoot transients on the input if the duration is less than 50-µs.

8.4 Device Functional Modes

Driving the EN pin over 1.2 V for V_1 between 2.2 V to 3.6 V or 1.35 V for V_1 between 3.6 V and 6.5 V turns on the regulator. Driving the EN pin below 0.4 V causes the regulator to enter shutdown mode.

In shutdown, the current consumption of the device is reduced to 0.02 µA typically.



9 Application and Implementation

9.1 Application Information

The TPS7A8101-Q1 device belongs to a family of new-generation LDO regulators that use innovative circuitry to achieve wide bandwidth and high loop gain, resulting in extremely high PSRR (over a 1-MHz range) even with very low headroom ($V_I - V_O$). A noise-reduction capacitor ($C_{(NR)}$) at the NR pin and a bypass capacitor ($C_{(BYPASS)}$) decrease noise generated by the bandgap reference in order to improve PSRR, while a quick-start circuit fast-charges the noise-reduction capacitor. This family of regulators offers sub-bandgap output voltages, current-limit, and thermal protection, and is fully specified from -40° C to 125° C.

9.2 Typical Application

Figure 31 shows the connections for the device.

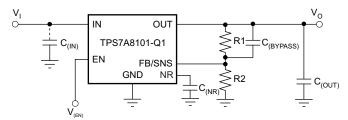


Figure 31. Typical Application Circuit

The voltage on the FB pin sets the output voltage and is determined by the values of the resistors R1 and R2. Use Equation 2 to calculate the values of R1 and R2 any voltage.

$$V_{\rm O} = \frac{(R1 + R2)}{R2} \times 0.8$$
 (2)

Table 1 lists sample resistor values for common output voltages. In Table 1, E96 series resistors are used, and all values meet 1% of the target V_O , assuming resistors with zero error. For the actual design, pay attention to any resistor error-factors. Using lower values for R1 and R2 reduces the noise injected into the FB pin.

9.2.1 Design Requirements

9.2.1.1 Dropout Voltage

The TPS7A8101-Q1 device uses a PMOS pass transistor to achieve low dropout. When $(V_I - V_{Onom})$ is less than the dropout voltage (V_{DO}) , the PMOS pass device is in the linear region of operation and the input-to-output resistance is the $r_{DS(on)}$ of the PMOS pass element. V_{DO} is proportional to the output current because the PMOS device in dropout functions in the same way as a resistor.

As with any linear regulator, PSRR and transient responses are degraded as $(V_1 - V_0)$ approaches dropout. Figure 19 and Figure 20 in the *Typical Characteristics* section shown this effect.

9.2.1.2 Minimum Load

The TPS7A8101-Q1 device is stable and functions well with no output load. Traditional PMOS-LDO regulators suffer from lower loop gain at very light output loads. The TPS7A8101-Q1 device employs an innovative low-current mode circuit to increase loop gain under very light or no-load conditions, resulting in improved output voltage regulation performance down to zero output current.

9.2.1.3 Input And Output Capacitor Requirements

Although an input capacitor is not required for stability, connecting a $0.1-\mu F$ to $1-\mu F$ low-equivalent series-resistance (ESR) capacitor from the input supply near the regulator to ground is good analog-design practice. This capacitor counteracts reactive input sources and improves transient response and ripple rejection. A higher-value capacitor may be necessary if large, fast load transients are anticipated or if the device is located several inches from the power source. If source impedance is not sufficiently low, a $0.1-\mu F$ input capacitor may be necessary to ensure stability.



Typical Application (continued)

The TPS7A8101-Q1 device is designed to be stable with standard ceramic capacitors of capacitance values 4.7 μ F or larger. This device was evaluated using a 10- μ F ceramic capacitor of 10-V rating, 10% tolerance, X5R type, and 0805 size (2 mm × 1,25 mm).

X5R-type and X7R-type capacitors are highly recommended because they have minimal variation in capacitance and ESR over temperature. The maximum ESR should be less than 1 Ω .

Table 1. Recommended Feedback Resistor Values for Common Output Voltages

Vo	R1	R2
0.8 V	0 Ω (Short)	10 kΩ
1 V	2.49 kΩ	10 kΩ
1.2 V	4.99 kΩ	10 kΩ
1.5 V	8.87 kΩ	10 kΩ
1.8 V	12.5 kΩ	10 kΩ
2.5 V	21 kΩ	10 kΩ
3.3 V	30.9 kΩ	10 kΩ
5 V	52.3 kΩ	10 kΩ

Table 2. Recommended Capacitor Values

NAME	DESCRIPTION	VALUE
C _(NR)	Noise-reduction capacitor between the NR and GND pins	470 nF
C _(BYPASS)	Noise-reduction capacitor across R1	470 nF
C _(OUTPUT)	Output capacitor	10 μF
C _(IN)	Input capacitor	10 μF

9.2.1.4 Transient Response

As with any regulator, increasing the size of the output capacitor reduces overshoot and undershoot magnitude but increases the duration of the transient response. Using a larger noise-reduction capacitor ($C_{(NR)}$), bypass capacitor ($C_{(RYPASS)}$), or both types of capacitors can improve line-transient performance.

9.2.2 Detailed Design Procedure

9.2.2.1 Output Noise

In most LDOs, the bandgap is the dominant noise source. If a noise reduction capacitor $(C_{(NR)})$ is used with the TPS7A8101-Q1 device, the bandgap does not contribute significantly to noise. Instead, noise is dominated by the output resistor-divider and the error-amplifier input. If a bypass capacitor $(C_{(BYPASS)})$ across the high-side feedback resistor (R1) is used with the TPS7A8101-Q1 device, noise from these other sources can also be significantly reduced.

To maximize noise performance in a given application, use a 0.47-μF noise-reduction capacitor plus a 0.47-μF bypass capacitor.



9.2.3 Application Curves

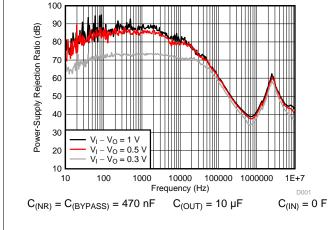


Figure 32. PSRR vs Frequency

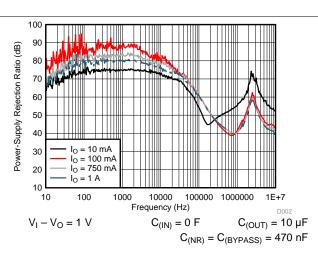


Figure 33. PSRR vs Frequency

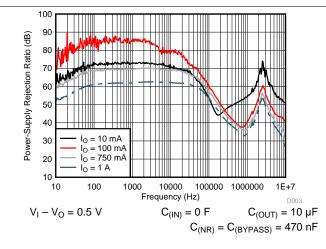


Figure 34. PSRR vs Frequency

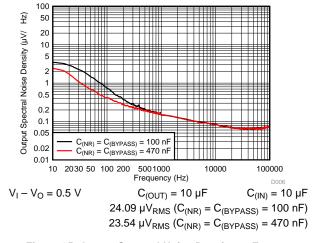


Figure 35. Output Spectral Noise Density vs Frequency (RMS noise (100 Hz to 100 kHz))

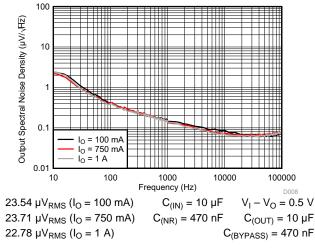


Figure 36. Output Spectral Noise Density vs Frequency (RMS noise (100 Hz to 100 kHz))

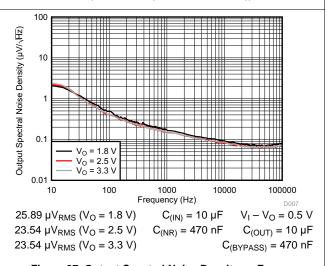
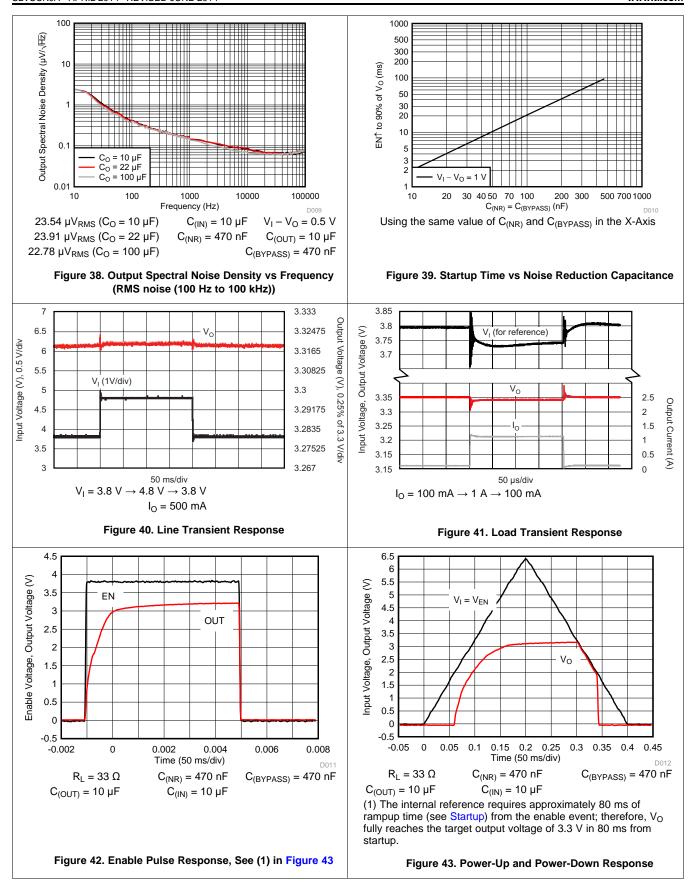


Figure 37. Output Spectral Noise Density vs Frequency (RMS noise (100 Hz to 100 kHz))

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10 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 2.2 V and 6.5 V. The input voltage range should provide adequate headroom in order for the device to have a regulated output. This input supply should be well regulated. If the input supply is noisy, additional input capacitors with low ESR can help improve the output noise performance.

11 Layout

11.1 Layout Guidelines

11.1.1 Board Layout Recommendations To Improve PSRR And Noise Performance

To improve AC performance such as PSRR, output noise, and transient response, designing with separate ground planes for V_I and V_O , with each ground plane connected only at the GND pin of the device, is recommended. In addition, the ground connection for the noise-reduction capacitor should connect directly to the GND pin of the device.

High ESR capacitors may degrade PSRR.

11.2 Layout Example

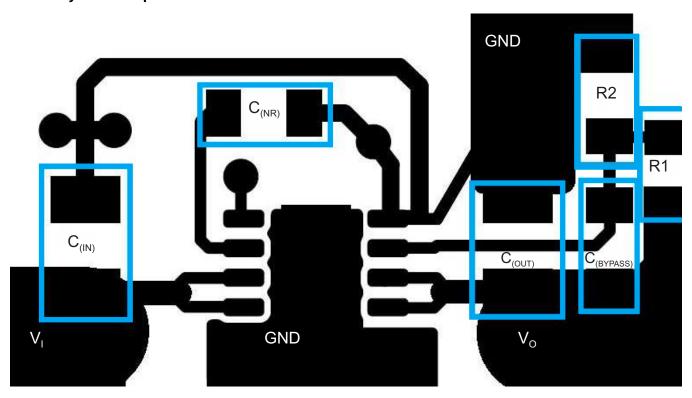


Figure 44. TPS7A8101-Q1 Layout Example



11.3 Thermal Information

11.3.1 Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately 160°C, allowing the device to cool. When the junction temperature cools to approximately 140°C the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the dissipation of the regulator, protecting it from damage because of overheating.

Any activation of the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to 125°C (maximum). To estimate the margin of safety in a complete design (including heatsink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection should trigger at least 35°C above the maximum expected ambient condition of your particular application. This configuration produces a worst-case junction temperature of 125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS7A8101-Q1 device has been designed to protect against overload conditions. The internal thermal protection circuitry was not intended to replace proper heatsinking. Continuously running the TPS7A8101-Q1 device into thermal shutdown degrades device reliability.

11.3.2 Package Mounting

See the Mechanical, Packaging, and Orderable Information section for solder pad footprint recommendations and recommended land patterns.

11.3.3 Power Dissipation

Knowing the device power dissipation and proper sizing of the thermal plane that is connected to the tab or pad is critical to avoiding thermal shutdown and ensuring reliable operation.

The power dissipation of the device depends on input voltage and load conditions. To calculate the device power dissipation, use Equation 3.

$$P_{D} = (V_{I} - V_{O}) \times I_{O} \tag{3}$$

Using the lowest possible input voltage necessary to achieve the required output voltage regulation minimizes power dissipation and achieves greater efficiency.

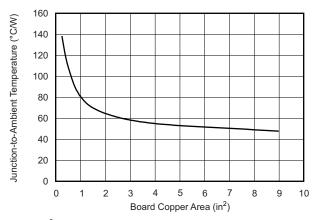
On the SON (DRB) package, the primary conduction path for heat is through the exposed pad to the printed circuit board (PCB). The pad can be connected to ground or can be left floating; however, the pad should be attached to an appropriate amount of copper PCB area to ensure the device does not overheat. The maximum junction-to-ambient thermal resistance depends on the maximum ambient temperature, maximum device junction temperature, and power dissipation of the device. Calculate the maximum junction-to-ambient thermal resistance using Equation 4.

$$R_{\theta JA} = \frac{\left(125^{\circ}C - T_{A}\right)}{P_{D}} \tag{4}$$

Once the maximum $R_{\theta JA}$ value is calculated, use Figure 45 to estimate the minimum amount of PCB copper area needed for appropriate heatsinking.



Thermal Information (continued)



Note: The $R_{\theta,JA}$ value at board size of 9 in² (that is, 3 in × 3 in) is a JEDEC standard.

Figure 45. R_{AJA} vs Board Size

Figure 45 shows the variation of $R_{\theta JA}$ as a function of ground plane copper area in the board. Figure 45 is intended as a guideline only to demonstrate the effects of heat spreading in the ground plane and should not be used to estimate actual thermal performance in real application environments.

NOTE

When the device is mounted on an application PCB, using Ψ_{JT} and Ψ_{JB} , as explained in the section is strongly recommended.

11.3.4 Estimating Junction Temperature

Using the thermal metrics Ψ_{JT} and Ψ_{JB} , as shown in the *Thermal Information* table, the junction temperature can be estimated with the corresponding equations, Equation 5 and Equation 6. For backwards compatibility, an older θ_{JC} , Top parameter is listed as well.

$$\varphi_{JT}$$
: $T_J = T_T + \varphi_{JT} \times P_D$

where

- P_D is the power dissipation (see Equation 4)
- T_T is the temperature at the center-top of the IC package

$$\varphi_{JB}$$
: $T_J = T_B + \varphi_{JB} \times P_D$

where

 T_B is the PCB temperature measured 1-mm away from the IC package on the PCB surface as shown in Figure 46

Product Folder Links: TPS7A8101-Q1

(5)



Thermal Information (continued)

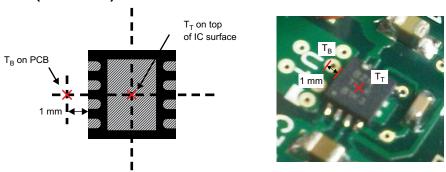


Figure 46. Measuring Points for T_T and T_B

NOTE

Both T_T and T_B can be measured on actual application boards using an infrared thermometer.

For more information about measuring T_T and T_B , see TI's application report SBVA025, *Using New Thermal Metrics*.

As shown in Figure 47, the new thermal metrics (Ψ_{JT} and Ψ_{JB}) have very little dependency on board size. That is, using Ψ_{JT} or Ψ_{JB} with Equation 5 is a good way to estimate T_J by simply measuring T_T or T_B , regardless of the application board size.

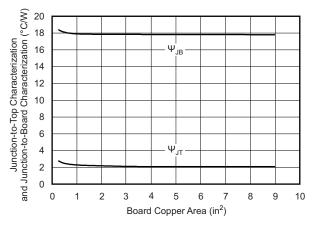


Figure 47. Ψ_{JT} and Ψ_{JB} vs Board Size

For a more detailed discussion of why TI does not recommend using $R_{\theta JC(top)}$ to determine thermal characteristics, refer to TI's application report SBVA025, *Using New Thermal Metrics*. For further information, refer to TI's application report SPRA953, *IC Package Thermal Metrics*.



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

- LDO noise examined in detail, SLYT489
- LDO Performance Near Dropout, SBVA029
- TPS7A8101EVM Evaluation Module, SLVU600
- Wide Bandwidth PSRR of LDOs by Nogawa and Van Renterghem in Bodo's Power Systems[®]: Electronics in Motion and Conversion, March 2011

12.2 Trademarks

Bodo's Power Systems is a registered trademark of Arlt Bodo. All other trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 31-Oct-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TPS7A8101QDRBRQ1	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SLY
TPS7A8101QDRBRQ1.A	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SLY

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS7A8101-Q1:

Catalog: TPS7A8101

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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NOTE: Qualified Version Definitions:

 $_{\bullet}$ Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A8101QDRBRQ1	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
TPS7A8101QDRBRQ1	SON	DRB	8	3000	346.0	346.0	33.0	



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4203482/L





PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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